



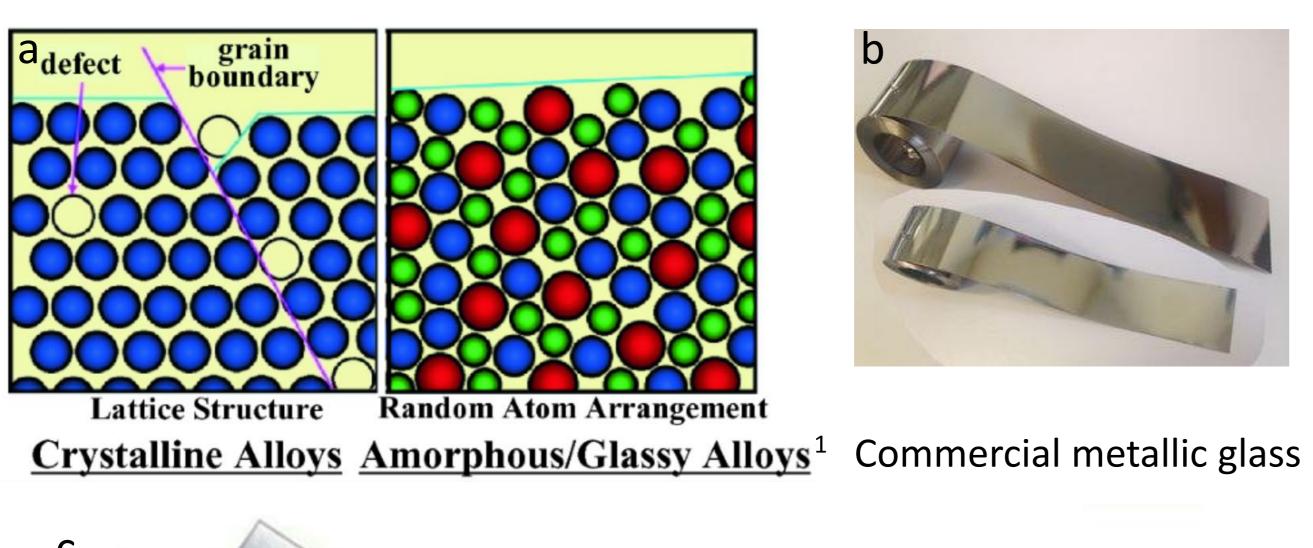
GRAPHENE AND 2DM VIRTUAL CONFERENCE & EXPO

Synthesis of uniform hexagonal boron nitride films on metallic glass by annealing

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Background: What is metallic glass?





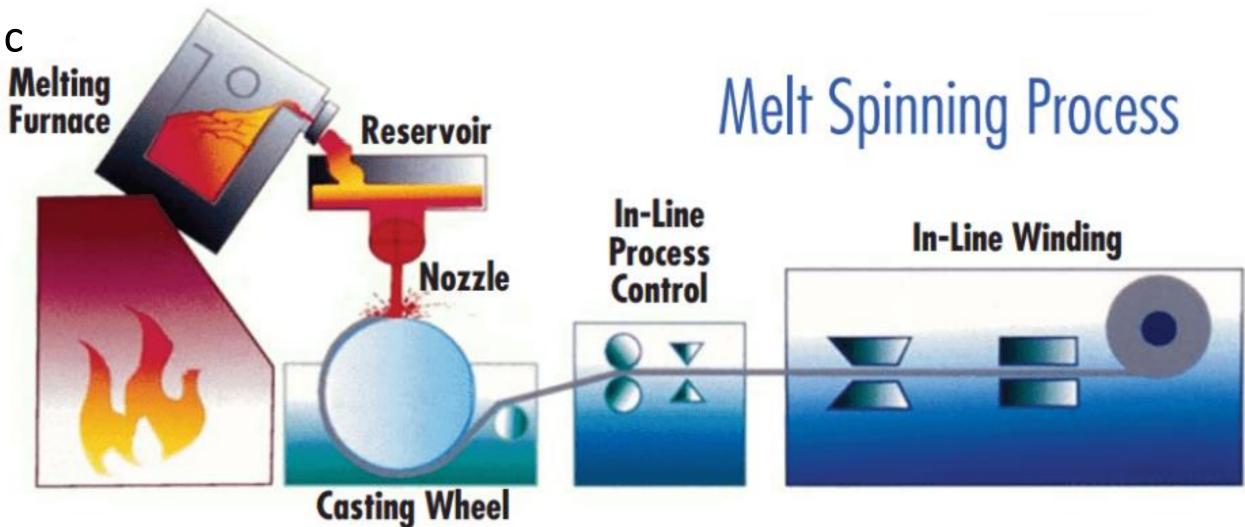


Fig. 1. (a) Difference between crystalline alloy and glassy alloy on the atomic scale. (b) Image of commercial metallic glass. (c) A processing schematic for metallic glass production. (Image from Metglas Inc.)

Methods

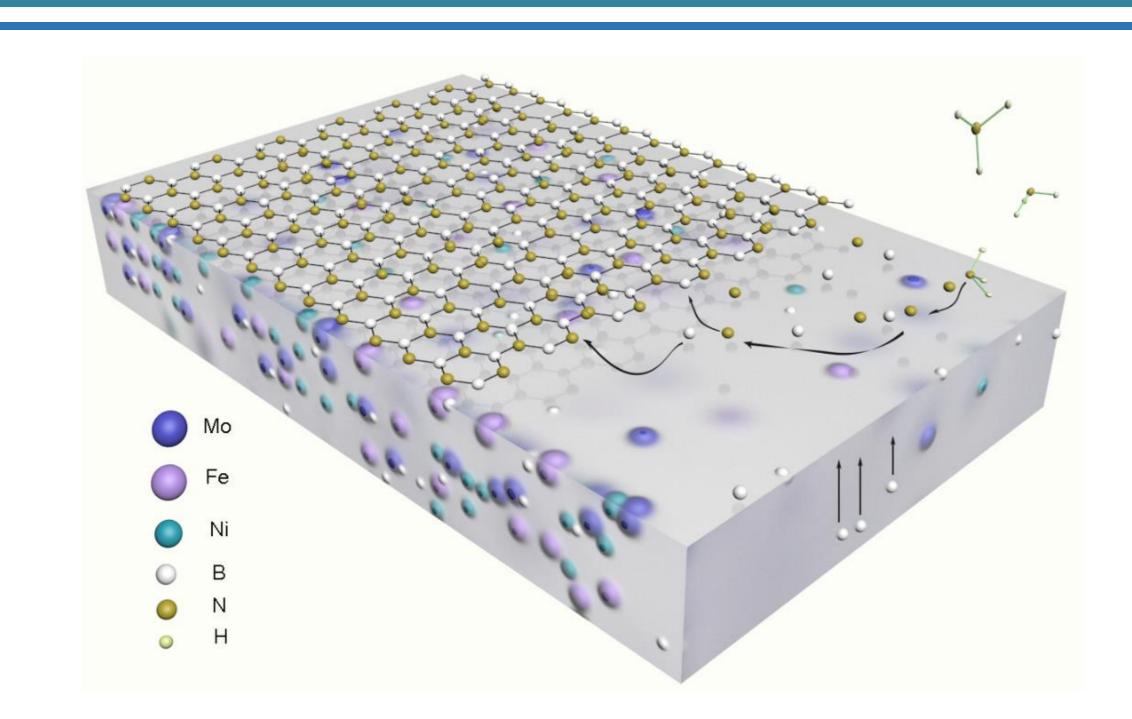


Fig. 2. Metallic glass $Fe_{40}Ni_{38}Mo_4B_{18}$ is used for the synthesis. During annealing in NH₃ atmosphere, boron atoms will diffuse to the surface and react with nitrogen atoms forming h-BN films.²

Results

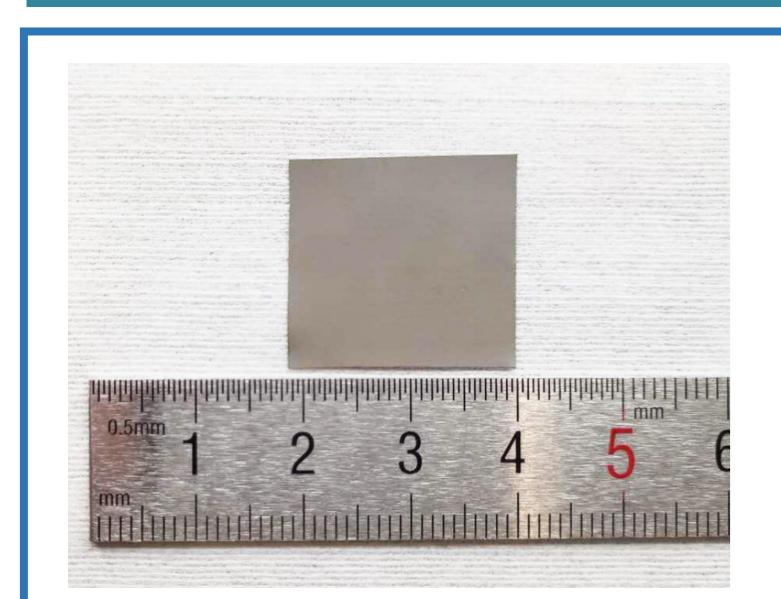




Fig. 3. Optical images of h-BN on metallic glass before (Left) and after (Right) transfer.

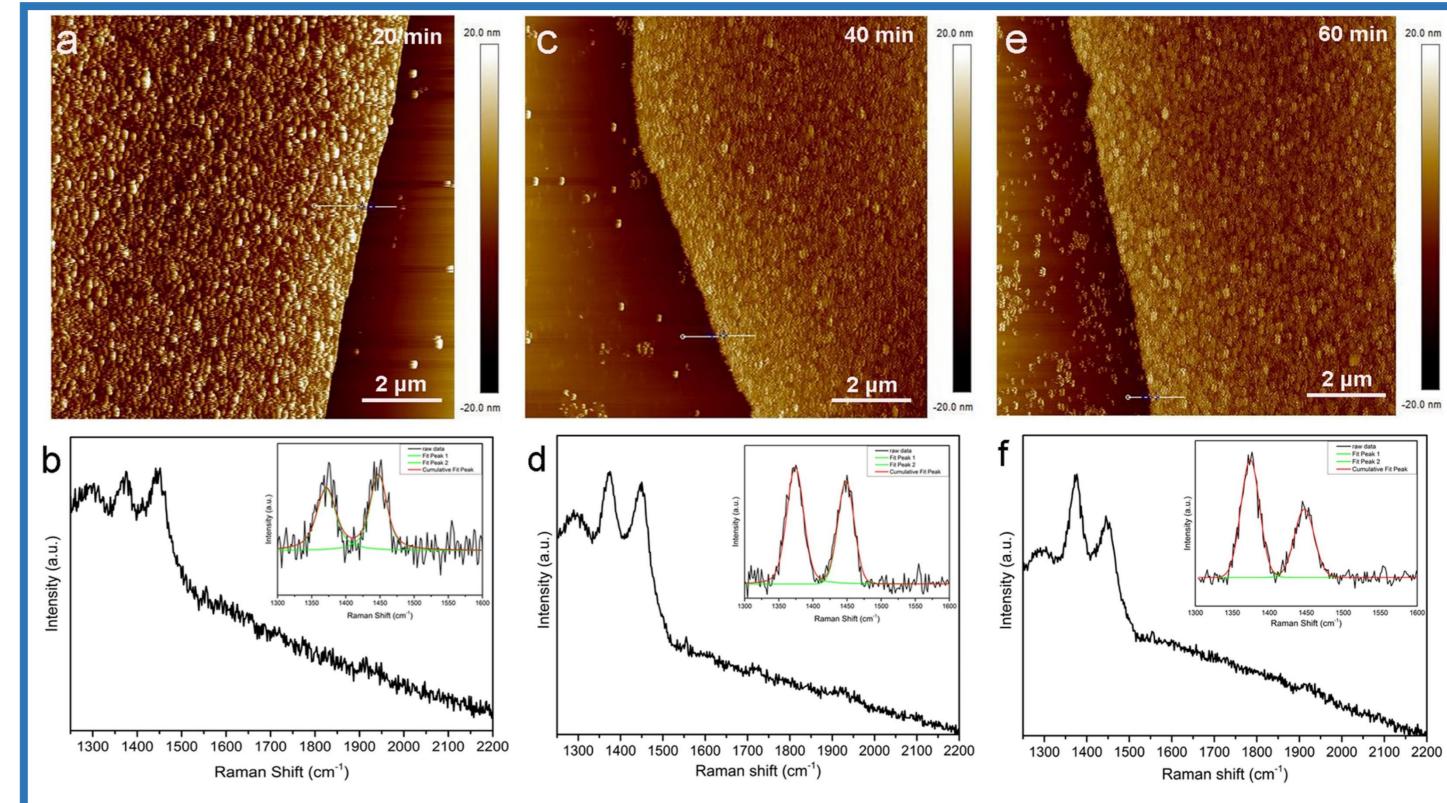


Fig. 4. AFM images of h-BN films synthesized by different annealing time after transfer. Increased ratio of E_{2g} to Si peak indicates enhanced crystallinity.

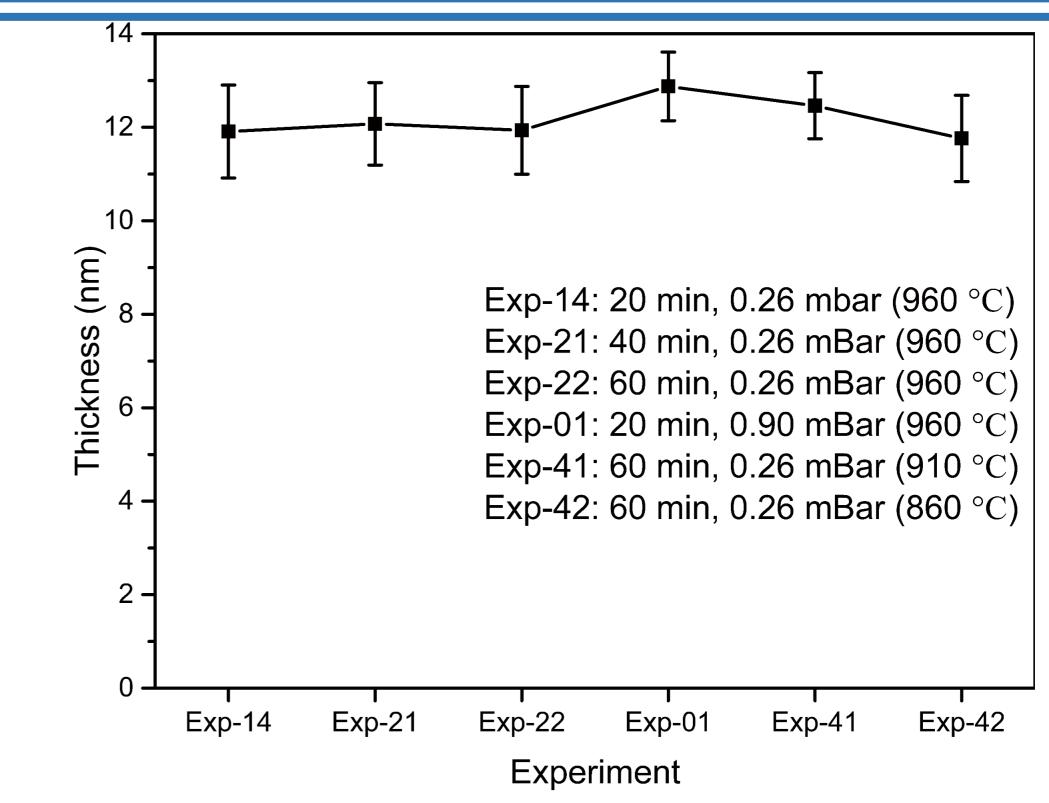


Fig. 5. Self-limited growth of h-BN films. Under different annealing conditions, h-BN films show quite similar thickness of ca. 12 nm.

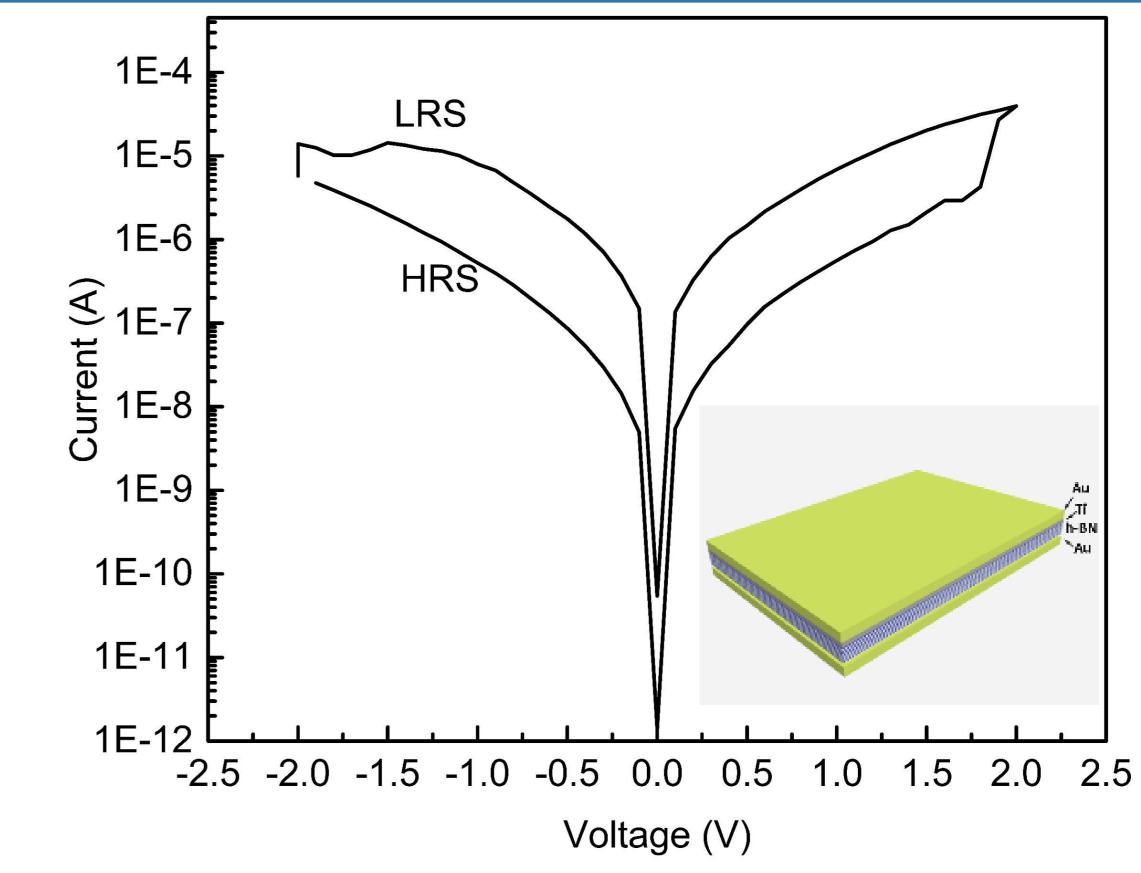


Fig. 6. Transition between low-resistance state (LRS) and high-resistance state (HRS) under different voltage of h-BN films.³ Inset shows the structure of the device. (Ongoing)

CONCLUSION

- 1 A low-cost method for h-BN synthesis on large scale is developed.
- 2 Films show high homogeneity in thickness due to self-limited growth.
- 3 Potential application in electronics is demonstrated.

REFERENCES

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